

C_1 is an extremely large value capacitor. 100 μA and 1 mA current sources are ideal. Neglect base current, Early effect, body effect, and CLM effect. Other data: for M_1 : $g_{m1} = 200 \mu\text{A/V}$, $C_{gs1} = 10 \text{ pF}$, $C_{gd1} = 1 \text{ pF}$, neglect C_{sb1} and C_{db1} ; for Q_2 : $\beta_2 = 200$, $C_{\pi 2} = 20 \text{ pF}$, $C_{\mu 2} = 2 \text{ pF}$.

- a) Evaluate the ac small-signal midband transresistance (v_0/i_s). 3
- b) Using ZVTC method, evaluate the fall time of v_0 for pulse response. 8
- c) Which capacitor is primarily responsible for this performance? Justify. 1

